

RELIABILITY REPORT
FOR
MAX1240BESA+

PLASTIC ENCAPSULATED DEVICES

October 22, 2009

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by			
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Quality Assurance			
Director, Reliability Engineering			



Conclusion

The MAX1240BESA+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim"s continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim"s quality and reliability standards.

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I. Device Description

A. General

The MAX1240/MAX1241 are low-power, 12-bit analog-to-digital converters (ADCs) available in 8-pin packages. The MAX1240 operates with a single +2.7V to +3.6V supply, and the MAX1241 operates with a single +2.7V to +5.25V supply. Both devices feature a 7.5µs successive-approximation ADC, a fast track/hold (1.5µs), an on-chip clock, and a high-speed, 3-wire serial interface. Power consumption is only 37mW (VDD = 3V) at the 73ksps maximum sampling speed. A 2µA shutdown mode reduces power at slower throughput rates. The MAX1240 has an internal 2.5V reference, while the MAX1241 requires an external reference. The MAX1241 accepts signals from 0V to VREF, and the reference input range includes the positive supply rail. An external clock accesses data from the 3-wire interface, which connects directly to standard microcontroller I/O ports. The interface is compatible with SPI™, QSPI™, and MICROWIRE™. Excellent AC characteristics and very low power combined with ease of use and small package size make these converters ideal for remote-sensor and data-acquisition applications, or for other circuits with demanding power consumption and space requirements. The MAX1240/MAX1241 are available in 8-pin DIP and SO packages.



II. Manufacturing Information

A. Description/Function: +2.7V, Low-Power, 12-Bit Serial ADCs in 8-Pin SO

B12 B. Process:

C. Number of Device Transistors:

D. Fabrication Location: Oregon, California or Texas E. Assembly Location: Malaysia, Philippines, Thailand

F. Date of Initial Production: September 25, 1997

III. Packaging Information

A. Package Type: 8-pin SOIC (N) B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin D. Die Attach: Conductive Epoxy E. Bondwire: Gold (1.3 mil dia.) F. Mold Material: Epoxy with silica filler G. Assembly Diagram: #05-2101-0015 H. Flammability Rating: Class UL94-V0 Level 1

I. Classification of Moisture Sensitivity per

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 170°C/W K. Single Layer Theta Jc: 40°C/W L. Multi Layer Theta Ja: 128.4°C/W M. Multi Layer Theta Jc: 36°C/W

IV. Die Information

A. Dimensions: 85 X 106 mils

B. Passivation: Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)

C. Interconnect: Al/0.5%Cu with Ti/TiN Barrier

D. Backside Metallization: None

E. Minimum Metal Width: 1.2 microns (as drawn) F. Minimum Metal Spacing: 1.2 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq. H. Isolation Dielectric: SiO₂ I. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Ken Wendel (Director, Reliability Engineering)

Bryan Preeshl (Managing Director of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppmD. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (\(\lambda \)) is calculated as follows:

$$\lambda = \underbrace{\frac{1}{\text{MTTF}}}_{\text{mTTF}} = \underbrace{\frac{1.83}{192 \times 4340 \times 160 \times 2}}_{\text{(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)}}_{\lambda = 6.71 \times 10^{-9}}$$

$$\lambda = 6.71 \times 10^{-9}$$

$$\lambda = 6.71 \text{ F.I.T. (60% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim"s reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the B12 Process results in a FIT Rate of 0.06 @ 25C and 1.06 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The AC18-6 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2000 V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250 mA.



Table 1Reliability Evaluation Test Results

MAX1240BESA+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	160	0	
	Biased	& functionality			
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
HAST	Ta = 130°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 96hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010	•			

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data